

0.25- Ω Low-Voltage Dual SPDT Analog Switch

DESCRIPTION

The DG3535/DG3536 is a sub 1 Ω (0.25 Ω at 2.7 V) dual SPDT analog switches designed for low voltage applications.

The DG3535/DG3536 has on-resistance matching (less than 0.05 Ω at 2.7 V) and flatness (less than 0.2 Ω at 2.7 V) that are guaranteed over the entire voltage range. Additionally, low logic thresholds makes the DG3535/DG3536 an ideal interface to low voltage DSP control signals.

The DG3535/DG3536 has fast switching speed with breakbefore-make guaranteed. In the On condition, all switching elements conduct equally in both directions. Off-isolation and crosstalk is - 69 dB at 100 kHz.

The DG3535/DG3536 is built on Vishay Siliconix's highdensity low voltage CMOS process. An eptiaxial layer is built in to prevent latchup. The DG3535/DG3536 contains the additional benefit of 2000 V ESD protection.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with the lead (Pb)-free device terminations. For MICRO FOOT analog switching products manufactured with tin/ silver/copper (SnAgCu) device terminations, the lead (Pb)-free "-E1" suffix is being used as a designator.

FEATURES

- Low Voltage Operation
- Low On-Resistance r_{ON} : 0.25 Ω at 2.7 V
- - 69 dB OIRR at 2.7 V, 100 kHz
- MICRO FOOT[®] Package
- ESD Protection > 2000 V

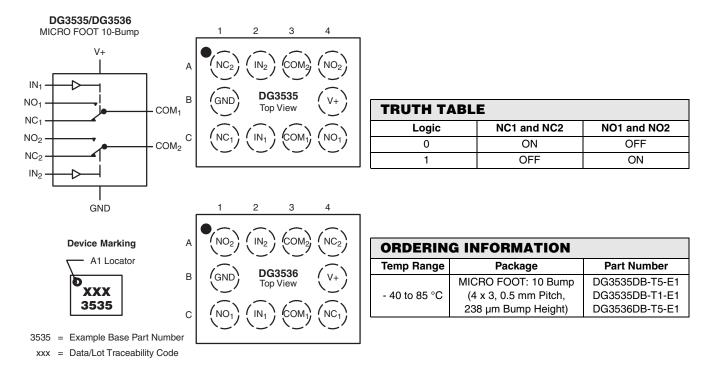
BENEFITS

- Reduced Power Consumption
- High Accuracy
- Reduce Board Space
- 1.6 V Logic Compatible
- High Bandwidth

APPLICATIONS

- Cellular Phones
- Speaker Headset Switching
- Audio and Video Signal Routing
- PCMCIA Cards
- · Battery Operated Systems
- Relay Replacement

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION





COMPLIANT



ABSOLUTE MAXIMUM RATINGS							
Parameter		Limit	Unit				
Reference V+ to GND		- 0.3 to + 6	V				
IN, COM, NC, NO ^a		- 0.3 to (V+ + 0.3 V)	V				
Continuous Current (NO, NC, COM)		± 300	mA				
Peak Current (Pulsed at 1 ms, 10 % duty	Current (Pulsed at 1 ms, 10 % duty cycle)						
Storage Temperature	(D Suffix)	- 65 to 150	°C				
Package Solder Reflow Conditions ^b	IR/Convection	250					
ESD per Method 3015.7	· · ·	> 2	kV				
Power Dissipation (Packages) ^c	MICRO FOOT: 10 Bump (4 x 3 mm) ^d	457	mW				

Notes:

a Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings. b Refer to IPC/JEDEC (J-STD-020B)

c All bumps welded or soldered to PC Board.

d Derate 5.7 mW/°C above 70 °C.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

SPECIFICATIONS (V+ = 3.0 V)							
		Test Conditions Otherwise Unless Specified		Limits - 40 to 85 °C			
Parameter	Symbol	V+ = 3 V, \pm 10 %,V $_{\rm IN}$ = 0.5 V or 1.4 V $^{\rm e}$	Temp ^a	Min ^b	Тур ^с	Max ^b	Unit
Analog Switch				•	•	•	
Analog Signal Range ^d	V _{NO} , V _{NC} , V _{COM}		Full	0		V+	v
On-Resistance ^d	r _{ON}		Room Full		0.25	0.4 0.5	
r _{ON} Flatness ^d	r _{ON} Flatness	V+ = 2.7 V, V _{COM} = 0.6/1.5 V I _{NO} , I _{NC} = 100 mA	Room			0.15	Ω
On-Resistance Match Between Channels ^d	$\Delta r_{DS(on)}$		Room			0.05	
Switch Off Leakage Current	I _{NO(off)} I _{NC(off)}	V+ = 3.3 V, V _{NO} , V _{NC} = 0.3 V/3 V, V _{COM} = 3 V/0.3 V	Room Full	- 2 - 20		2 20	nA
	I _{COM(off)}		Room Full	- 2 - 20		2 20	
Channel-On Leakage Current	I _{COM(on)}	V+ = 3.3 V, V _{NO} , V _{NC} = V _{COM} = 0.3 V/3 V	Room Full	- 2 - 20		2 20	
Digital Control							
Input High Voltage ^d	V _{INH}		Full	1.4			v
Input Low Voltage	V _{INL}		Full			0.5	
Input Capacitance	C _{in}		Full		10		pF
Input Current	$I_{\rm INL}$ or $I_{\rm INH}$	$V_{IN} = 0$ or V+	Full	1		1	μA



SPECIFICATIONS (V+ = 3.0 V)								
		Test ConditionsOtherwise Unless SpecifiedV+ = 3 V, ± 10 %, VIN = 0.5 V or 1.4 Ve	Temp ^a	Limits - 40 to 85 °C				
Parameter	Symbol			Min ^b	Тур ^с	Max ^b	Unit	
Dynamic Characteristics								
Turn-On Time	t _{ON}	V _{NO} or V _{NC} = 2.0 V, R _L = 50 Ω, C _L = 35 pF	Room Full		52	82 90		
Turn-Off Time	t _{OFF}		Room Full		43	73 78	ns	
Break-Before-Make Time	t _d		Room	1	6		1	
Charge Injection ^d	Q _{INJ}	C_L = 1 nF, V_{GEN} = 1.5 V, R_{GEN} = 0 Ω	Full		21		рС	
Off-Isolation ^d	OIRR	$R_1 = 50 \Omega, C_1 = 5 pF, f = 100 kHz$	Room		- 69		dD	
Crosstalk ^d	X _{TALK}	$h_{\rm L} = 30.32, 0 = 3.00, 1 = 100 \text{ M}/2$	Room		- 69		dB	
N_O , N_C Off Capacitance ^d	C _{NO(off)}	V _{IN} = 0 or V+, f = 1 MHz	Room		145		- pF	
	C _{NC(off)}		Room		145			
Channel-On Capacitance ^d	C _{NO(on)}		Room		406			
	C _{NC(on)}		Room		406			
Power Supply	•	•	÷		•	-		
Power Supply Current	l+	V _{IN} = 0 or V+	Room Full		0.001	1.0 1.0	μA	

Notes:

a. Room = 25 °C, Full = as determined by the operating suffix.

b. Typical values are for design aid only, not guaranteed nor subject to production testing.

c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

d. Guarantee by design, nor subjected to production test.

e. V_{IN} = input voltage to perform proper function.

- 40 °C

2.0

1111

100 K

INO(off), INC(off)

2.5

3.0

₽

10 M

1 M

I_{COM(on)}

85 °C

0.5

1.0

25 °C

1.5

V_{COM} - Analog Voltage (V)

10 K

Input Switching Frequency (Hz)

1 K

V + = 3.0 V

╘ШШ

100

0.5

1.0

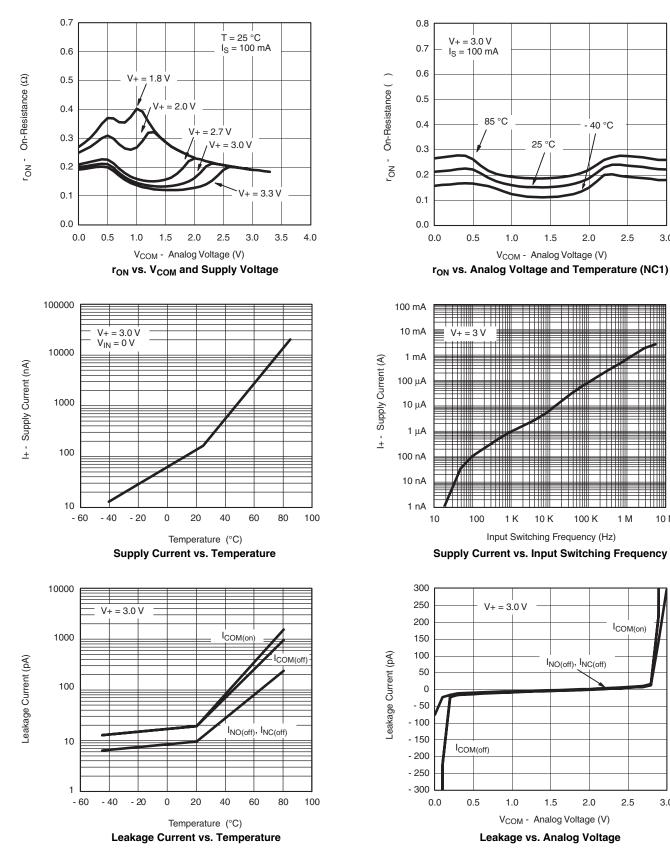
1.5

V_{COM} - Analog Voltage (V)

Leakage vs. Analog Voltage

Vishay Siliconix

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



2.5

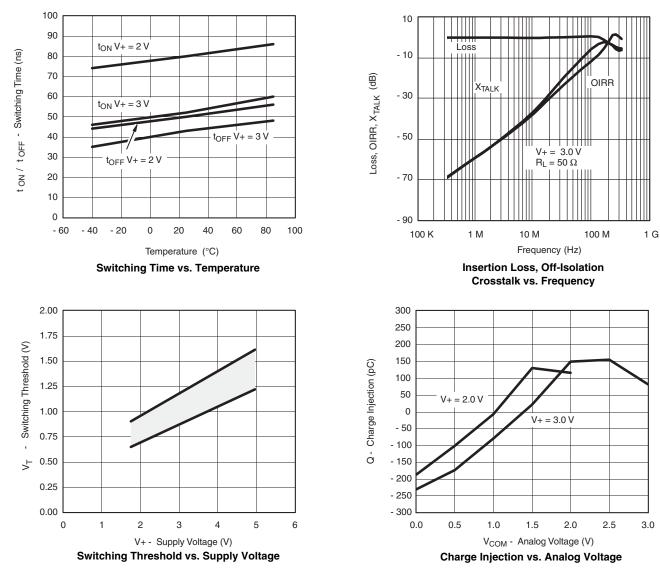
3.0

2.0





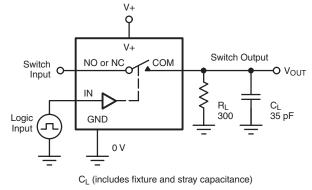
VISHAY

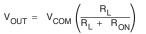


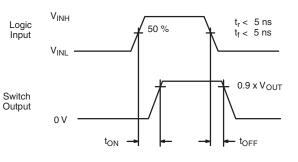
DG3535/DG3536

Vishay Siliconix

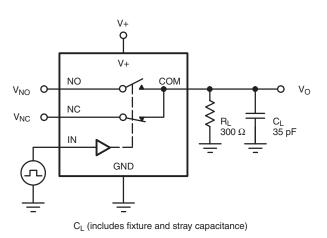
TEST CIRCUITS

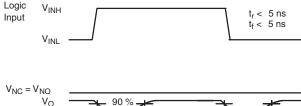






Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.





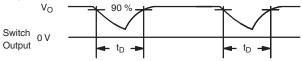
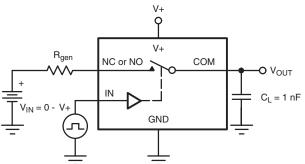
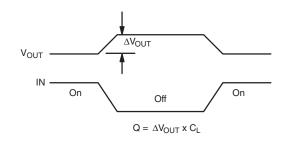


Figure 2. Break-Before-Make Interval

Figure 1. Switching Time





IN depends on switch configuration: input polarity determined by sense of switch.







DG3535/DG3536

Vishay Siliconix

TEST CIRCUITS

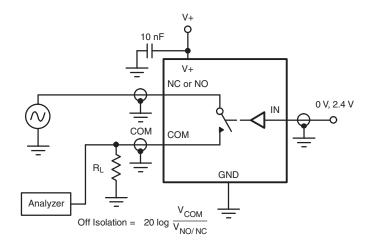


Figure 4. Off-Isolation

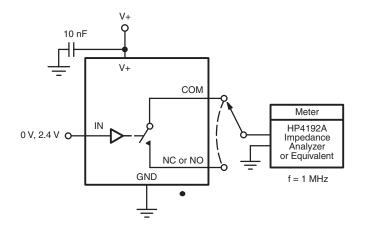
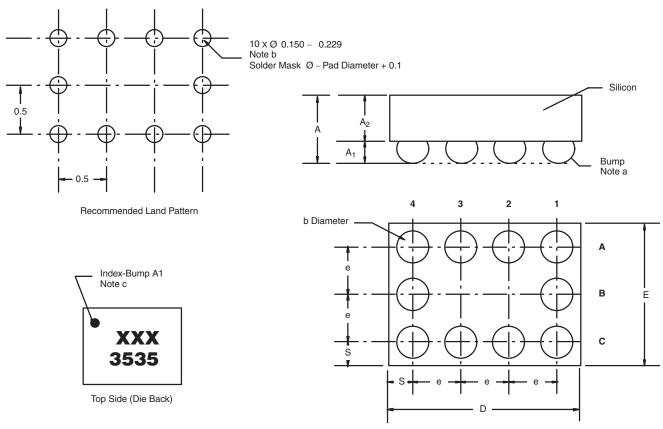


Figure 5. Channel Off/On Capacitance

PACKAGE OUTLINE

MICRO FOOT: 10 BUMP (4 x 3, 0.5 mm PITCH, 0.238 mm BUMP HEIGHT)



Notes (Unless Otherwise Specified):

a. Bump is Lead Free Sn/Ag/Cu.

b. Non-solder mask defined copper landing pad.

c. Laser Mark on silicon die back; back-lapped, no coating. Shown is not actual marking; sample only.

Dim	Millimeters ^a		Inches			
	Min	Max	Min	Мах		
Α	0.688	0.753	0.0271	0.0296		
A ₁	0.218	0.258	0.0086	0.0102		
A ₂	0.470	0.495	0.0185	0.0195		
b	0.306	0.346	0.0120	0.0136		
D	1.980	2.020	0.0780	0.0795		
E	1.480	1.520	0.0583	0.0598		
е	0.5 BASIC		0.0197 BASIC			
S	0.230	0.270	0.0091	0.0106		

Notes:

a. Use millimeters as the primary measurement.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?72961.

ISHA



Vishay

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.